NSN 5961-00-044-5759

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View Online at https://aerobasegroup.com/nsn/5961-00-044-5759 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: -35.0 breakdown voltage, collector-to-base, emitter open and -35.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** -100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 240.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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